

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2997	semiconductor with (ldd light adj dop\$3) and (gate scan\$4) with (taper\$3 thick\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:05
L2	3118	257/59	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:12
L3	252	2 and 1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:06
L4	2095	semiconductor with (ldd light adj dop\$3) and (gate scan\$4) with (taper\$3 thick\$4) and (gate scan\$4) adj2 electrode with (first second)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:28
L5	231	2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:07
L6	556	semiconductor with (ldd light adj dop\$3) and (gate scan\$4) with (taper\$3 thick\$4) and second adj2 (gate scan\$4) adj2 electrode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:07
L7	72	2 and 6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:12
L8	2697	257/72	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:14

L9	73	8 and 6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:13
L10	1823	349/43	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:15
L11	25	10 and 6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:16
L12	1555	349/42	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:19
L13	27	12 and 6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:16
L14	839	349/138	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:17
L15	6	14 and 6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:17
L16	273	349/41	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:17

L17	2	16 and 6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:19
L18	62	349/52	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:19
L19	0	18 and 6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:19
L20	0	18 and 1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:19
L21	9	16 and 1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:19
L22	87	(semiconductor with (ldd light adj dop\$3) and (gate scan\$4) with (taper\$3 thick\$4) and (gate scan\$4) adj2 electrode with (first second)). clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/23 08:29